

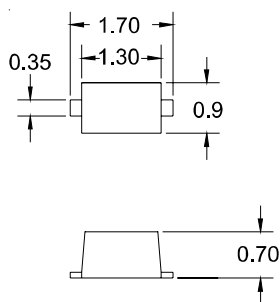
## Description

The DC1251D5 is a 12V uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The DC1251D5 complies with the IEC 61000-4-2 (ESD) with  $\pm 30\text{kV}$  air and  $\pm 30\text{kV}$  contact discharge. It is assembled into an ultra-small lead-free SOD-523 package. The small size and high ESD surge protection make DC1251D5 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

## Mechanical Characteristics

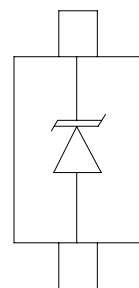
- ◆ Package: SOD-523
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

## Dimensions and Pin Configuration



Maximum Dimensions (mm)

Package Dimensions



SOD-523 (Top View)

Circuit and Pin Schematic

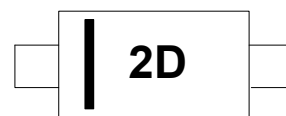
## Features

- ◆ Protects one data or power line
- ◆ Ultra low leakage: nA level
- ◆ Operating voltage: 12V
- ◆ Low clamping voltage
- ◆ Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 30\text{kV}$
    - Contact discharge:  $\pm 30\text{kV}$
  - IEC61000-4-5 (Lightning) 13A (8/20 $\mu\text{s}$ )
- ◆ ROHS Compliant

## Applications

- ◆ Cellular Handsets and Accessories
- ◆ Personal Digital Assistants
- ◆ Notebooks and Handhelds
- ◆ Portable Instrumentation
- ◆ Digital Cameras
- ◆ Peripherals
- ◆ Audio Players

## Marking Information



2D = Device Marking Code  
Bar denotes Cathode

## Ordering Information

Part Number	Marking	Packaging	Reel Size
DC1251D5	2D	3000/Tape & Reel	7 inch

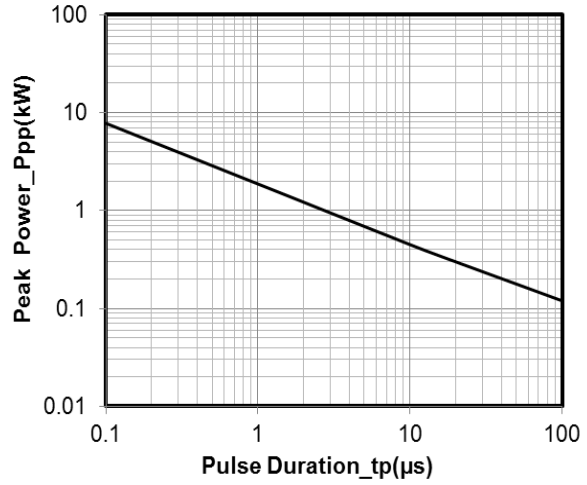
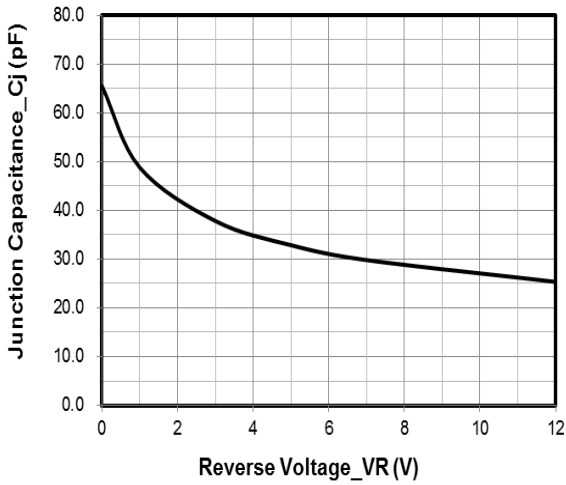
### **Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$ unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 $\mu\text{s}$ )	Ppk	300	W
Peak Pulse Current (8/20 $\mu\text{s}$ )	Ipp	13	A
ESD per IEC 61000-4-2 (Air)	VESD	$\pm 30$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 30$	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

### **Electrical Characteristics ( $T_A=25^{\circ}\text{C}$ unless otherwise specified)**

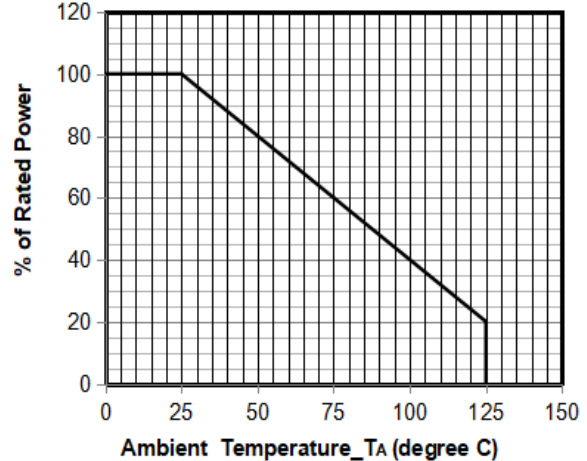
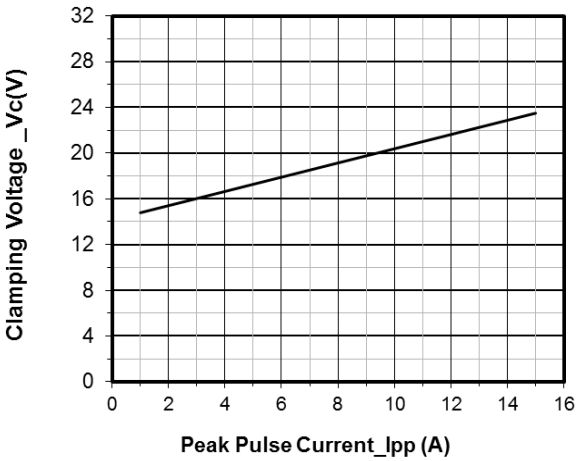
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			12	V	
Breakdown Voltage	VBR	13.3			V	$I_T = 1\text{mA}$
Reverse Leakage Current	$I_R$			0.2	$\mu\text{A}$	$V_{RWM} = 12\text{V}$
Forward Voltage	VF		1.0	1.2	V	$I_F = 10\text{mA}$
Clamping Voltage	VC			16	V	$I_{PP} = 1\text{A}$ (8 x 20 $\mu\text{s}$ pulse)
Clamping Voltage	VC			24	V	$I_{PP} = 13\text{A}$ (8 x 20 $\mu\text{s}$ pulse)
Junction Capacitance	CJ		65		pF	$V_R = 0\text{V}$ , $f = 1\text{MHz}$

**Typical Performance Characteristics (TA=25°C unless otherwise Specified)**



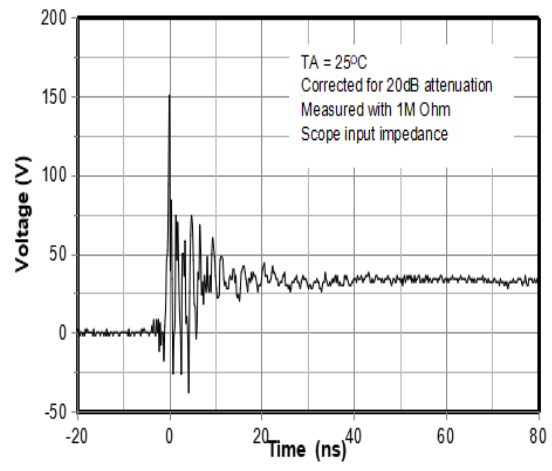
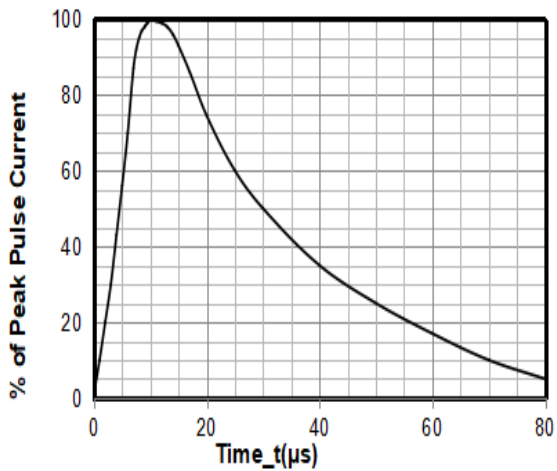
**Junction Capacitance vs. Reverse Voltage**

**Peak Pulse Power vs. Pulse Time**



**Clamping Voltage vs. Peak Pulse Current**

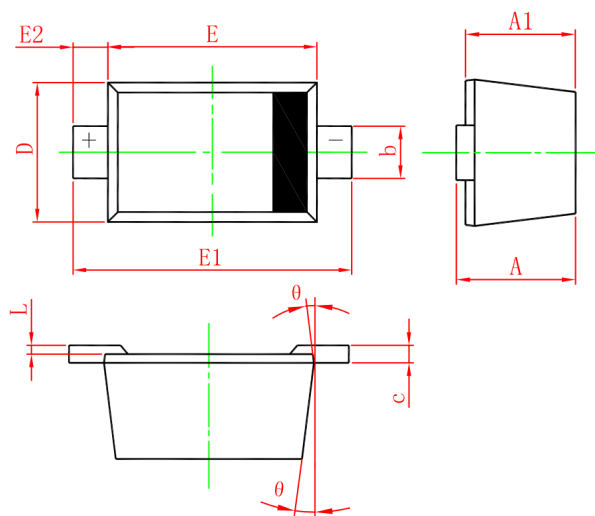
**Power Derating Curve**



**8 X 20μs Pulse Waveform**

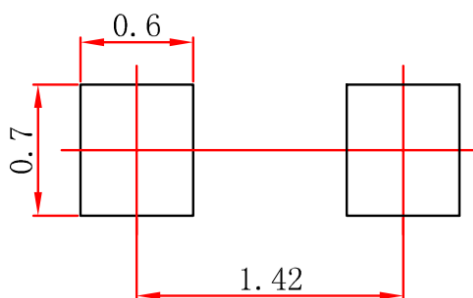
**ESD Clamping Voltage  
8 kV Contact per IEC61000-4-2**

## SOD-523 Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.51	--	0.77	0.020	--	0.031
A1	0.50	--	0.70	0.020	--	0.028
b	0.25	--	0.35	0.010	--	0.014
c	0.08	--	0.15	0.003	--	0.006
D	0.75	--	0.85	0.030	--	0.033
E	1.10	--	1.30	0.043	--	0.051
E1	1.50	--	1.70	0.059		0.067
E2	0.20REF			0.008REF		
L	0.01	--	0.07	0.001	--	0.003
Θ	7° REF			7° REF		

## Suggested Land Pattern



Unit : mm

## Contact Information

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